

# RBA019N10R1SBQ4

## REXFET-1 N-Channel [Power MOSFET](#)

100 V - 230 A - 1.9 mΩ - TOLL for Automotive

### Description

The RBA019N10R1SBQ4 N-channel power MOSFET features REXFET-1 split-gate technology and is offered in a TOLL package. The TOLL package features top-side cooling for ultra-compact and optimal thermal performance. Renesas' REXFET-1 split gate technology is suitable for applications requiring low RDS(on) and switching capability for high-power and high-frequency applications.

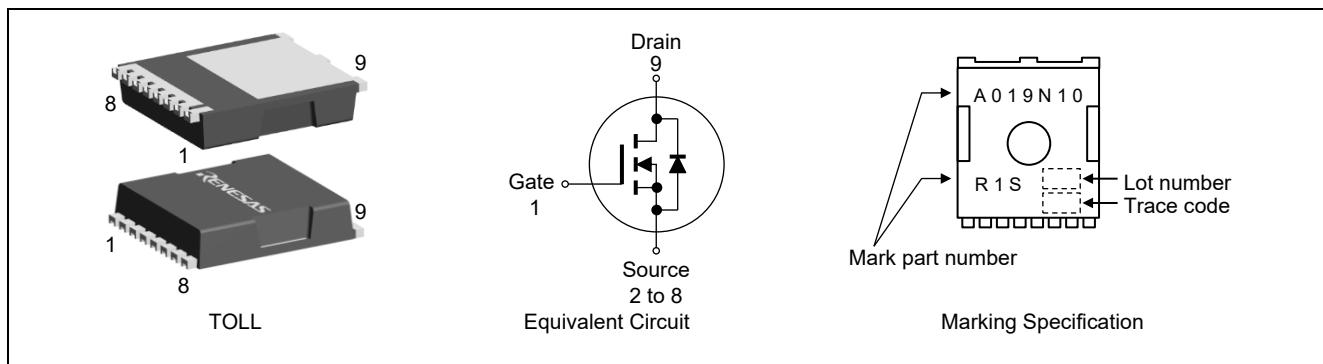
### Features

- Standard level gate drive voltage:  $V_{GS(th)} = 2.0$  to  $4.0$  V
- Super low on-state resistance:  $R_{DS(on)} = 1.9$  mΩ Max.
- Low input capacitance
- Low thermal resistance
- 100% Avalanche tested
- AEC-Q101 qualified, PPAP capable
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

### Application

Small Traction (2-wheel, 3-wheel vehicle), 48 V load, Onboard charger, Charging station, Low voltage DC/DC

### Outline



### Absolute Maximum Ratings

( $T_j = 25$  °C unless otherwise notice.)

Item	Symbol	Ratings	Unit
Drain to Source Voltage	$V_{DSS}$	100	V
Gate to Source Voltage	$V_{GSS}$	$\pm 20$	V
Drain Current (DC)	$I_{D(DC)}$ <small>T<sub>c</sub>=25°C Note 2,6</small>	$\pm 230$	A
	$I_{D(DC)}$ <small>T<sub>c</sub>=100°C Note 2,6</small>	$\pm 193$	A
Drain Current (pulse)	$I_{D(pulse)}$ <small>Note 1,3,6</small>	$\pm 920$	A
Power Dissipation	$P_D$ <small>Note 1,6</small>	405	W
Operating Junction Temperature	$T_j$	-55 to 175	°C
Storage Temperature	$T_{stg}$	-55 to 175	°C
Single Avalanche Current	$I_{AS}$ <small>Note 4</small>	55	A
Single Avalanche Energy	$E_{AS}$ <small>Note 4</small>	302	mJ

## Thermal Resistance

Item	Symbol	Max.	Unit
Junction to Case Thermal Resistance	$R_{th(j-c)}$ Note 6	0.37	°C/W
Junction to Ambient Thermal Resistance	$R_{th(j-a)}$ Note 5,6	40	°C/W

## Electrical Characteristics

( $T_j = 25$  °C unless otherwise notice.)

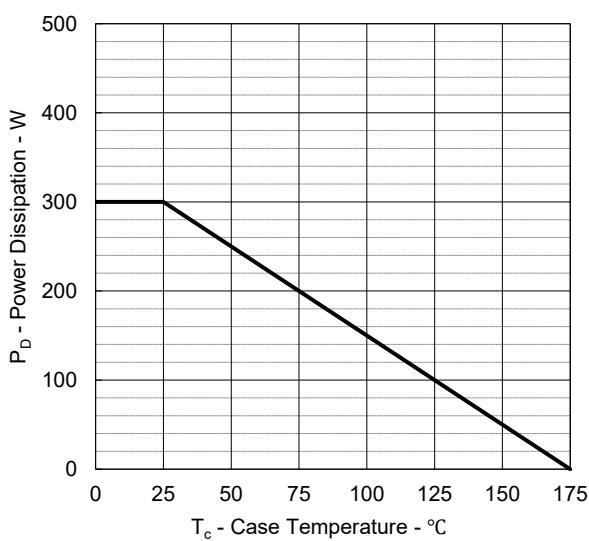
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	10	$\mu A$	$V_{DS} = 100$ V, $V_{GS} = 0$ V
Gate Leakage Current	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20$ V, $V_{DS} = 0$ V
Gate to Source Threshold Voltage	$V_{GS(th)}$	2.0	—	4.0	V	$V_{DS} = V_{GS}$ , $I_D = 250$ $\mu A$
Drain to Source On-state Resistance	$R_{DS(on)}$	—	1.63	1.9	$m\Omega$	$V_{GS} = 10$ V, $I_D = 100$ A
Input Capacitance	$C_{iss}$	—	11000	—	pF	$V_{DS} = 50$ V $V_{GS} = 0$ V $f = 100$ kHz
Output Capacitance	$C_{oss}$	—	2500	—	pF	
Reverse Transfer Capacitance	$C_{rss}$	—	70	—	pF	
Gate resistance	$R_g$	—	2.1	—	$\Omega$	—
Turn-on Delay Time	$t_{d(on)}$	—	65	—	ns	$V_{DD} = 50$ V $I_D = 100$ A $V_{GS} = 10$ V $R_G = 5$ $\Omega$
Rise Time	$t_r$	—	50	—	ns	
Turn-off Delay Time	$t_{d(off)}$	—	125	—	ns	
Fall Time	$t_f$	—	45	—	ns	
Total Gate Charge	$Q_g$	—	140	—	nC	$V_{DD} = 50$ V $V_{GS} = 10$ V $I_D = 100$ A
Gate to Source Charge	$Q_{gs}$	—	60	—	nC	
Gate to Drain Charge	$Q_{gd}$	—	25	—	nC	
Gate plateau voltage	$V_{plateau}$	—	5.5	—	V	$V_{DD} = 50$ V, $V_{GS} = 0$ V $I_F = 100$ A, $V_{GS} = 0$ V $I_F = 100$ A, $V_{GS} = 0$ V $di/dt = 100$ A/ $\mu s$
Output Charge	$Q_{oss}$	—	220	—	nC	
Body Diode Forward Voltage	$V_{F(S-D)}$	—	0.87	1.5	V	
Reverse Recovery Time	$t_{rr}$	—	100	—	ns	
Reverse Recovery Charge	$Q_{rr}$	—	250	—	nC	

Note 1.  $T_c = 25$  °C

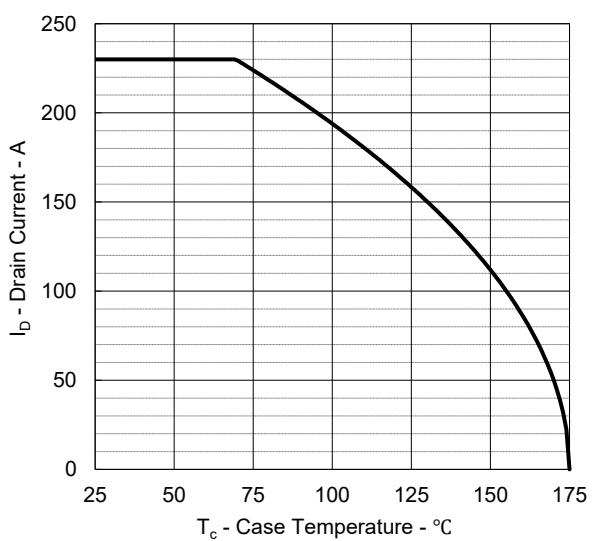
2. Value is limited by overall system design including PCB.
3.  $PW \leq 10$   $\mu s$
4.  $L = 100$   $\mu H$ ,  $V_{DD} = 50$  V,  $R_G = 25$   $\Omega$
5. Device on 40 mm x 40 mm x 1.5 mm epoxy PCB FR4. (2 oz Cu pad.)
6. Defined by design. Not subject to production test.

## Typical Characteristics

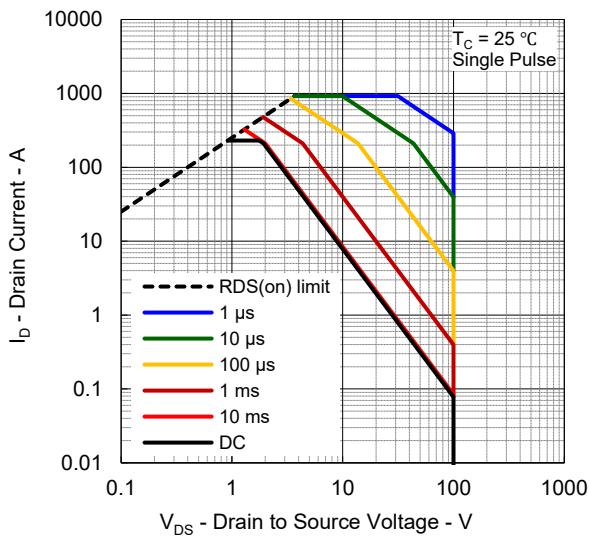
POWER DISSIPATION vs. CASE TEMPERATURE



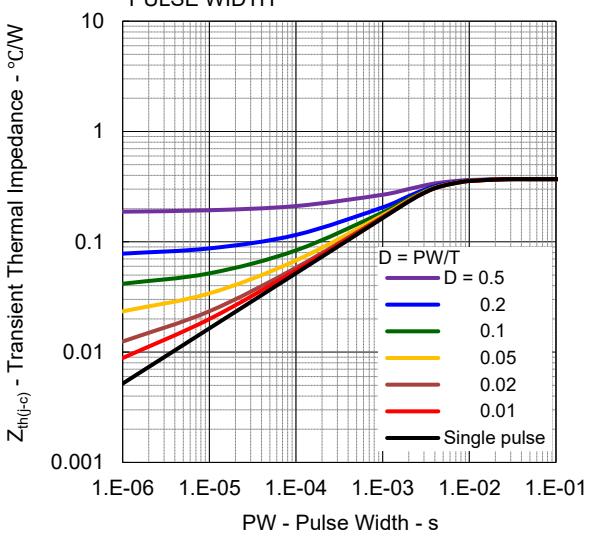
DRAIN CURRENT vs. CASE TEMPERATURE



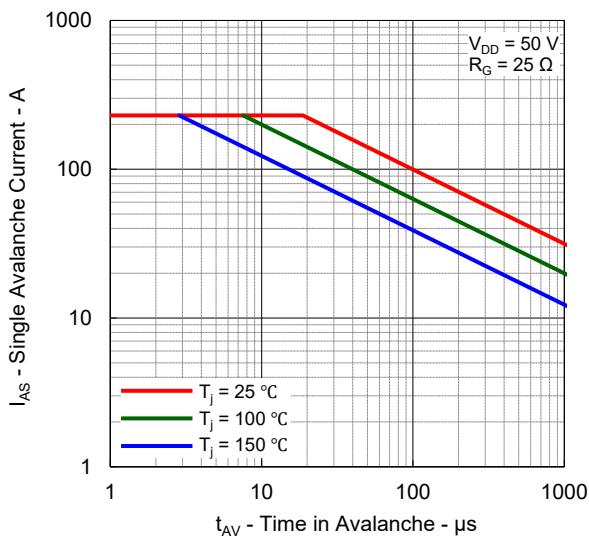
FORWARD BIAS SAFE OPERATING AREA



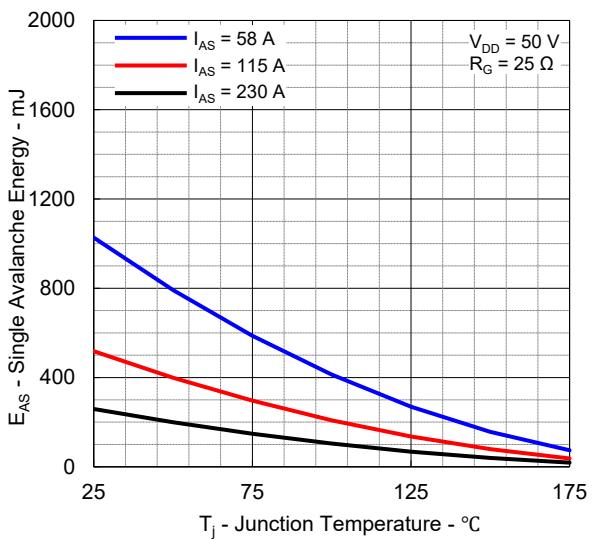
TRANSIENT THERMAL IMPEDANCE vs. PULSE WIDTH



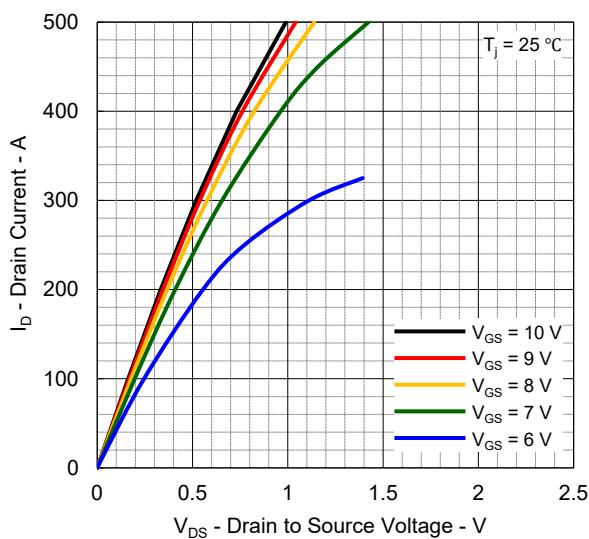
TYPICAL AVALANCHE CHARACTERISTICS



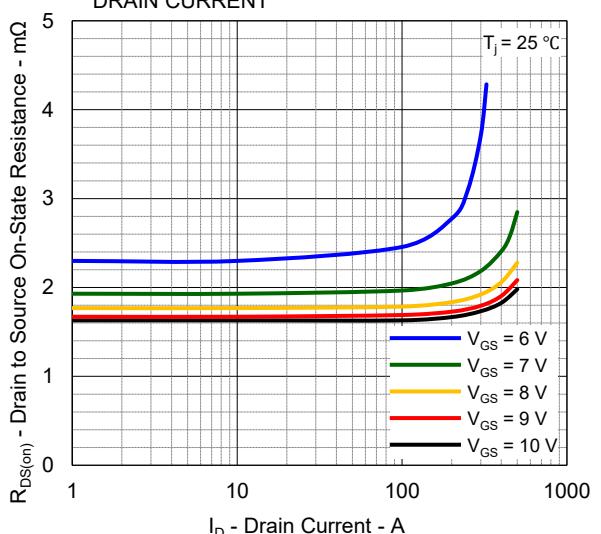
TYPICAL AVALANCHE ENERGY



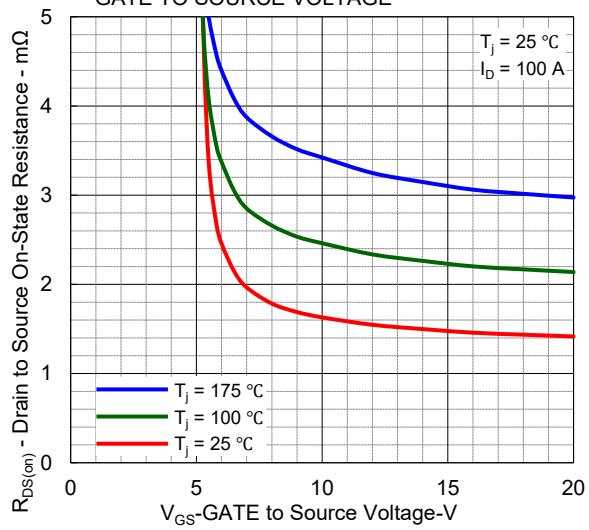
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



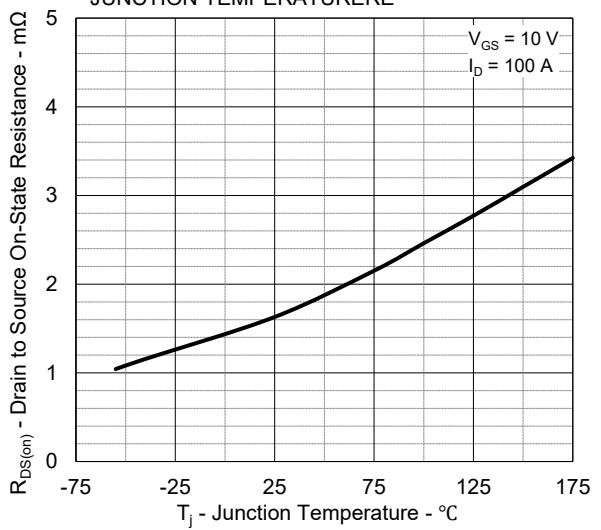
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



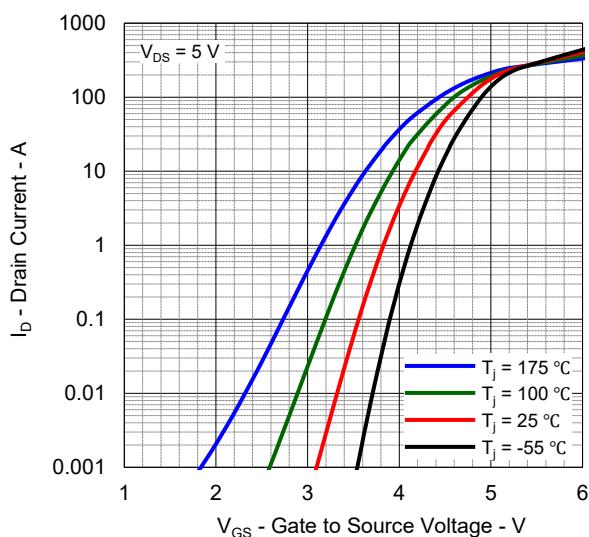
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



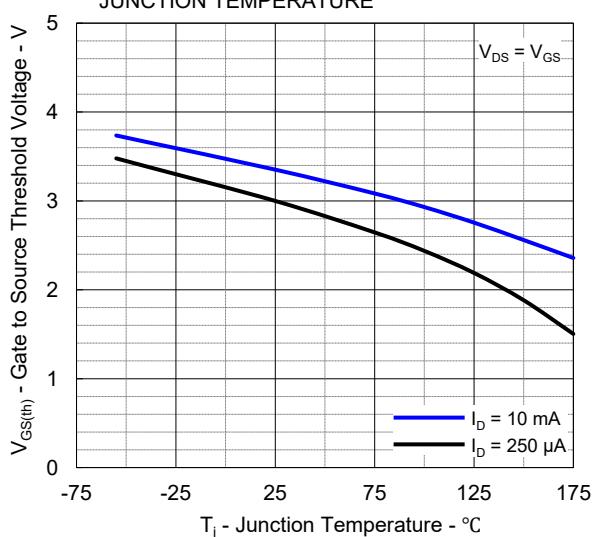
DRAIN TO SOURCE ON-STATE RESISTANCE vs. JUNCTION TEMPERATURE

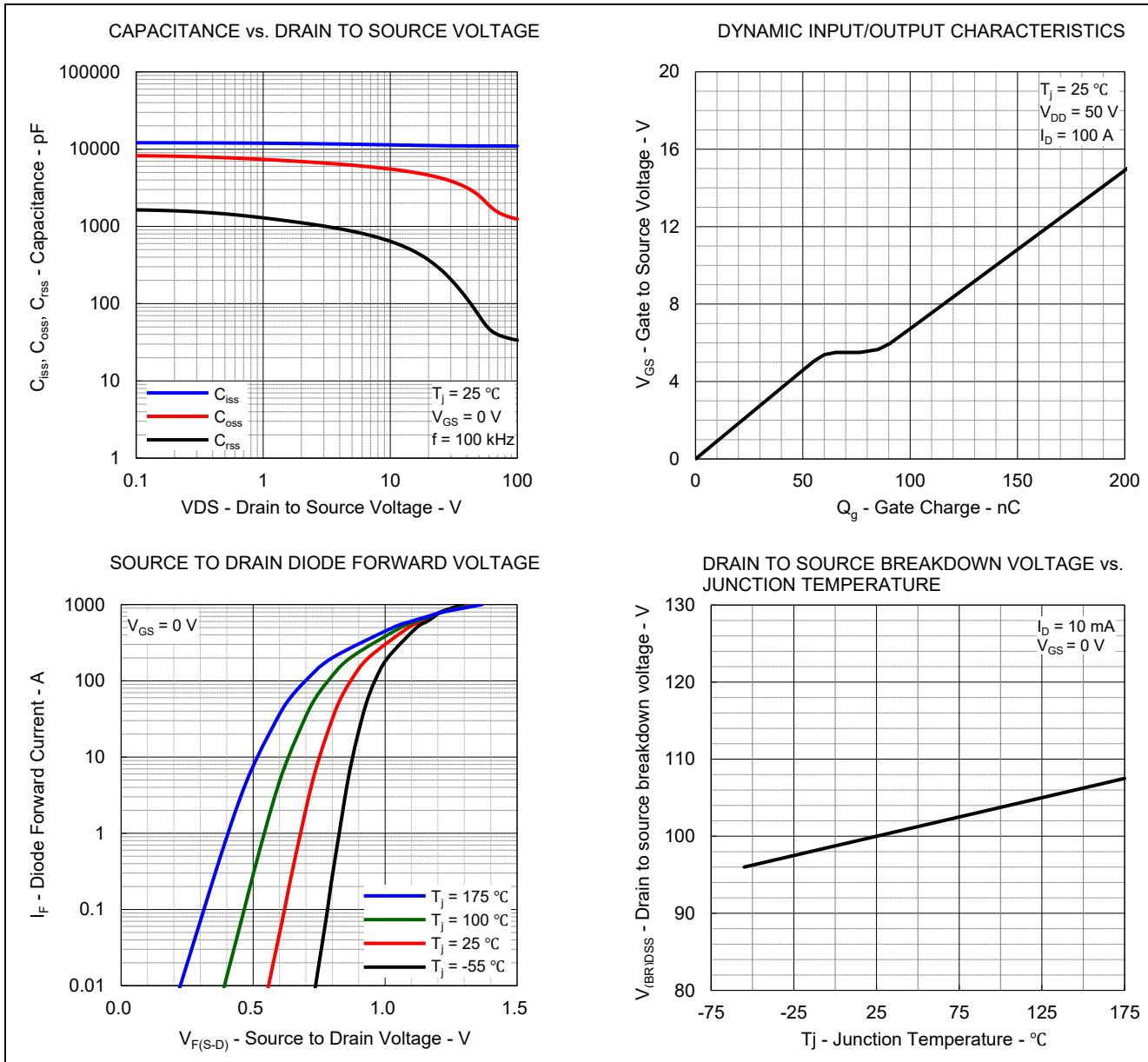


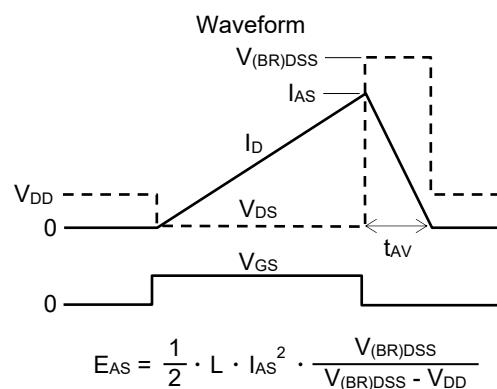
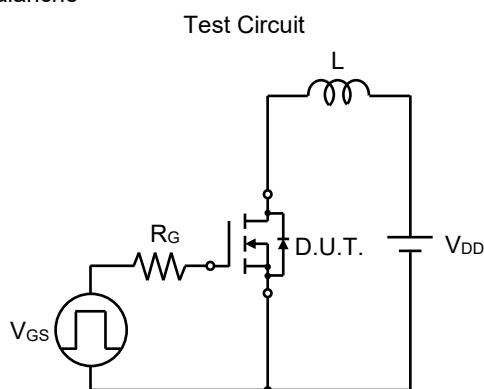
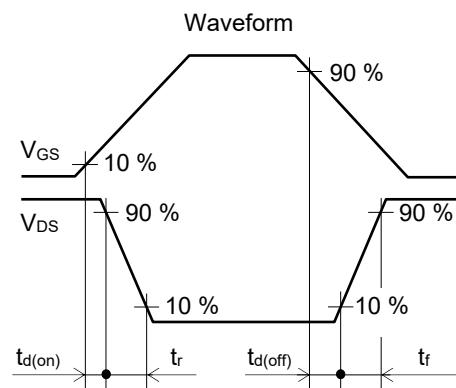
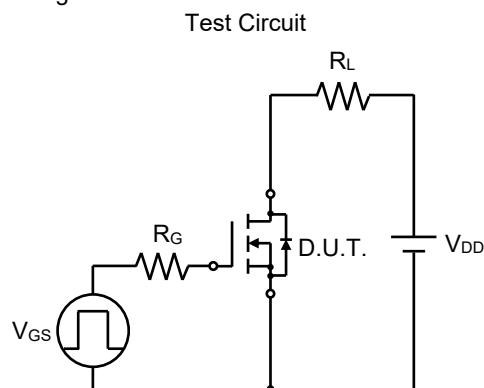
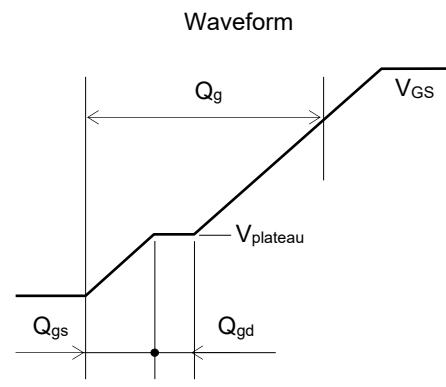
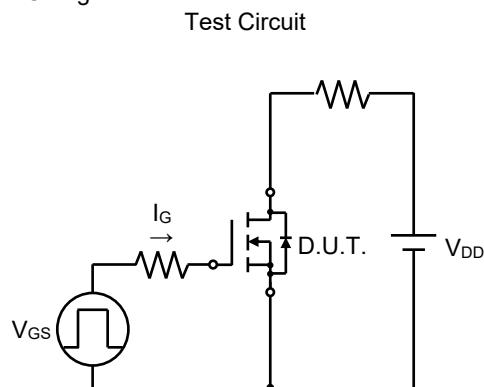
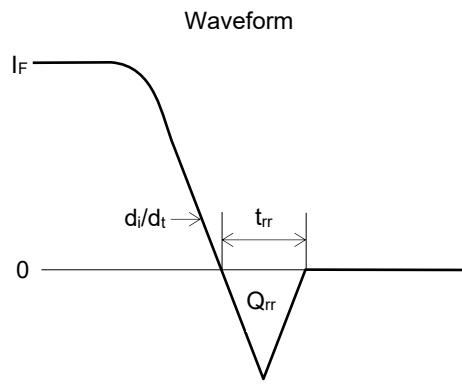
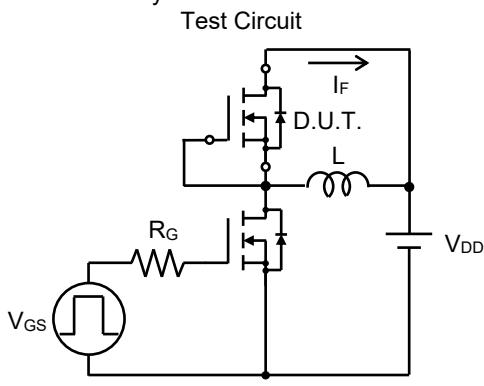
FORWARD TRANSFER CHARACTERISTICS



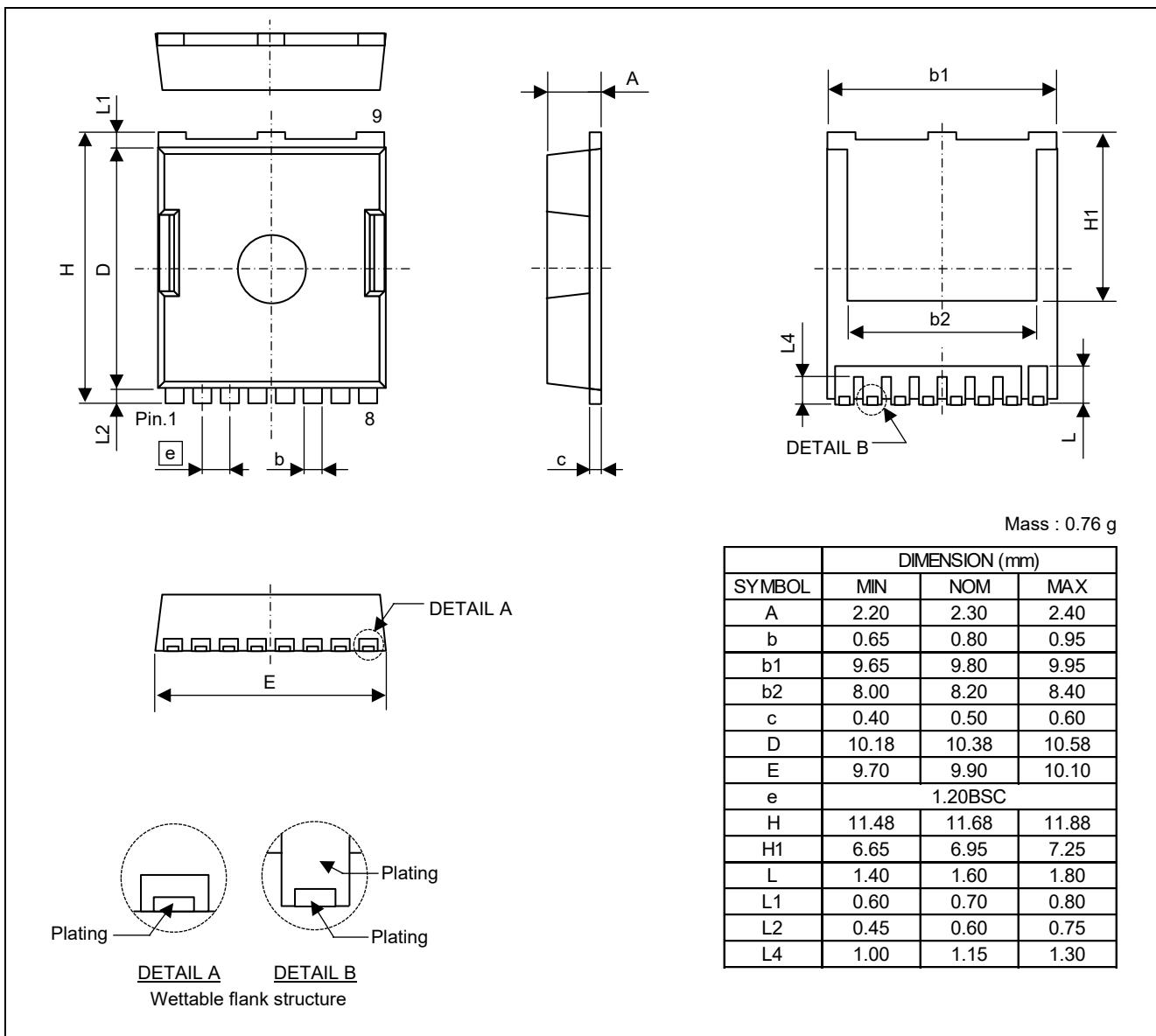
GATE TO SOURCE THRESHOLD VOLTAGE vs. JUNCTION TEMPERATURE



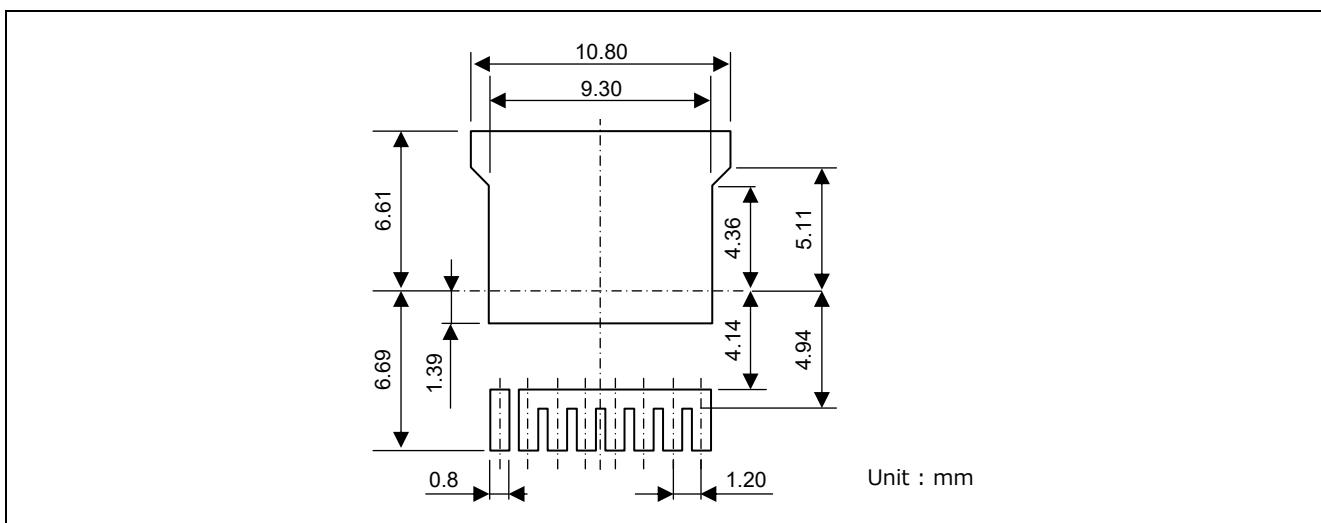


**Test Circuit****Avalanche****Switching Time****Gate Charge****Reverse Recovery**

## Package Dimensions



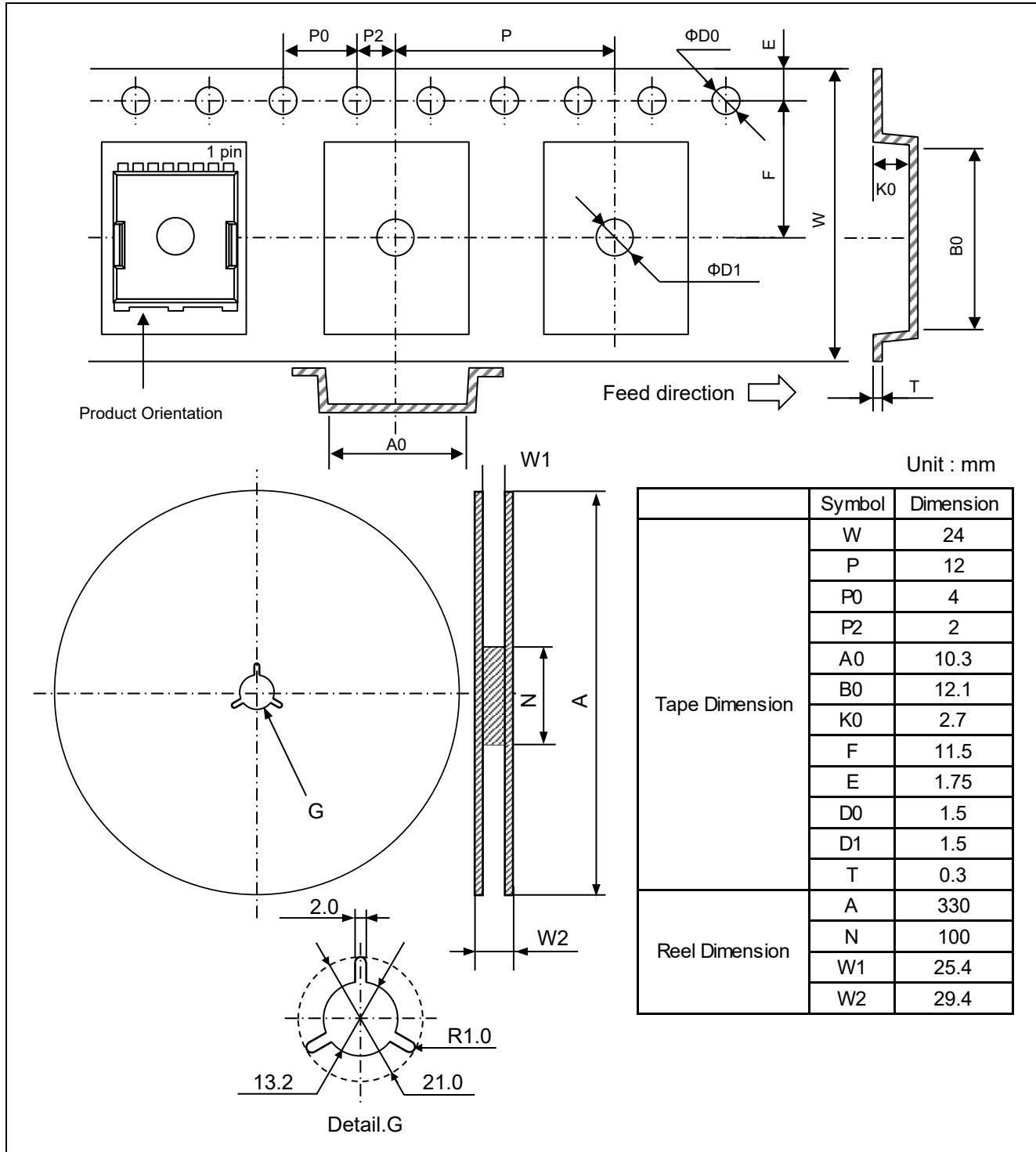
## Mount pad



## Ordering Information

Part No.	Packing	Quantity
RBA019N10R1SBQ4#GBO	Taping	2000pcs/reel

## Packing Specification



Remark : Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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## Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,  
Koto-ku, Tokyo 135-0061, Japan

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